









	<h2 style="color: red;">FQU1N80TU</h2> <p>Hersteller-Teilenummer: FQU1N80TU</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 1A IPAK</p> <p>Datenblätter:  FQU1N80TU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7385 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQU1N80TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 800V 1A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7385 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	2.5W (Ta), 45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1A (Tc)
Rds On (Max) @ Id, Vgs	20 Ohm @ 500mA, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	195pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQU1N80TU ist neu im Original, Suche FQU1N80TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU1N80TU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU1N80TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQU1N60TU Fairchild/ON Semiconductor MOSFET N-CH 600V 1A IPAK</p>	 <p>FQU1N60TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1A IPAK</p>	 <p>FQU20N06L F FQU20N06L F</p>	 <p>FQU20N06LTU Fairchild/ON Semiconductor MOSFET N-CH 60V 17.2A IPAK</p>
 <p>FQU20N06LTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 17.2A IPAK</p>	 <p>FQU20N06TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 16.8A IPAK</p>	 <p>FQU1N80TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 1A IPAK</p>	 <p>FQU1N60CTU Fairchild/ON Semiconductor MOSFET N-CH 600V 1A IPAK</p>

heiße Teile

Mehr

 FQU11P06	 FQU11P06TU	 FQU11P06TU	 FQU12N20	 FQU12N20L
 FQU12N20TU	 FQU12N20TU	 FQU13N06	 FQU13N06L	 FQU13N06LTU
 FQU13N06LTU	 FQU13N10	 FQU13N10L	 FQU13N10LTU	 FQU13N10LTU
 FQU17N08L	 FQU17P06	 FQU17P06TU	 FQU17P06TU	 FQU1N50C
 FQU1N60B	 FQU1N60C	 FQU1N60CTU	 FQU1N60CTU	 FQU1N80TU
 FQU20N06	 FQU20N06L	 FQU20N06LTU	 FQU20N06LTU	 FQU2N50B
 FQU2N50BTU	 FQU2N50BTU	 FQU2N60/SSU2N60	 FQU2N60A	 FQU2N60B
 FQU2N60C	 FQU2N60CTU	 FQU2N60CTU	 FQU2N65C	 FQU2N90TU
 FQU2N90TU	 FQU30N06L	 FQU3N40TU	 FQU3N40TU	 FQU3N50C
 FQU3N50CTU	 FQU3N50CTU	 FQU3N60C	 FQU3N60CTU	 FQU3N60CTU

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